Product data sheet Characteristics

XUBLBPCNM12

photo-electric sensor - XUB - thru beam - laser - Sn 100m - 12..24VDC - M12

Main

Commercial Status	Commercialised
Range of product	OsiSense XU
Series name	Application material handling
Electronic sensor type	Photo-electric sensor
Sensor name	XUB
Sensor design	Cylindrical M18
Detection system	Thru beam
Material	Metal
Type of output signal	Discrete
Supply circuit type	DC
Wiring technique	3-wire
Discrete output type	PNP
Discrete output function	1 NO or 1 NC programmable
Electrical connection	1 male connector M12
Emission	Red laser, wavelength: 670 nm (class 1) conforming to IEC 825-1
[Sn] nominal sensing distance	100 m

Complementary

Complementary		
Enclosure material	Nickel plated brass	
Lens material	PMMA	
Blind zone	0 mm	
Output type	Solid state	
Status LED	LED (yellow) for output state and alignment aid LED (red) for stability LED (green) for supply on and teaching	
[Us] rated supply voltage	1224 V DC with reverse polarity protection	
Supply voltage limits	1030 V DC	
Switching capacity in mA	<= 100 mA (overload and short-circuit protection)	
Switching frequency	1500 Hz	
Voltage drop	<= 1.5 V (closed state)	
Current consumption	25 mA (no-load)	
Power consumption in W	< 1 W	
Delay first up	< 80 ms	
Delay response	< 0.4 ms	
Delay recovery	< 0.4 ms	
Setting-up	With sensitivity adjustment	
Product weight	0.13 kg	
Kit composition	Transmitter + receiver XUBLBKCNM12T + XUBLBPCNM12	

Environment

Product certifications	CE CSA UL
Ambient air temperature for operation	-4070 °C
Ambient air temperature for storage	-1045 °C
Vibration resistance	7 gn, amplitude = +/- 0.75 mm (f = 1055 Hz) conforming to IEC 60068-2-6
Shock resistance	30 gn (duration = 11 ms) conforming to IEC 60068-2-27
IP degree of protection	IP67 (double insulation) conforming to IEC 60529

RoHS compliance

RoHS EUR status	Compliant
RoHS EUR conformity date(YYWW)	0901

Contractual warranty

Period 18 months

